

7MBR35VM120-50

IGBT Modules

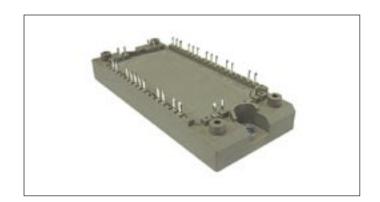
IGBT MODULE (V series) 1200V / 50A / PIM

■ Features

Low V_{CE}(sat)
Compact Package
P.C.Board Mount Module
Converter Diode Bridge Dynamic Brake Circuit
RoHS compliant product

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
Collector-Emit	ctor-Emitter voltage V _{CES}		1200	V			
Gate-Emitter v	tter voltage V _{GES}			±20	V		
Collector curr		Ic	Continuous	Tc=80°C	35		
	Collector current	Icp	1ms	Tc=80°C	70	Α	
Collector curre		-lc			35	А	
		-lc pulse	1ms		70		
Collector power dissipation		Pc	1 device		210	W	
Collector-Emitter voltage		Vces				V	
Gate-Emitter voltage		V _{GES}			±20	V	
Collector curre	rent	Ic	Continuous	Tc=80°C	25	۸	
Collector curre		Іср	1ms	Tc=80°C	50	Α	
Collector power dissipation		Pc	1 device	1 device		W	
Repetitive pea	Repetitive peak reverse voltage (Diode)				1200	V	
Repetitive pea	k reverse voltage	VRRM			1600	V	
Average output current		lo	50Hz/60Hz, sine wave		35	Α	
Average output current Surge current (Non-Repetitive)		IFSM	10ms, Tj=150°C		260	Α	
I²t (Non-Repetitive)		I²t	half sine wave		338	A ² s	
Junction temperature		т:	Inverter, Brake		175	- - - °C	
		Tj	Converter		150		
Operating junciton temperature (under switching conditions)		T:	Inverter, Brake		150		
		Tjop	Converter		150	C	
Case temperature		Tc			125		
Storage temperature		Tstg			-40 to +125		
olation voltage	between terminal and copper base (*1) between thermistor and others (*2)	Viso	AC : 1min.		2500	VAC	
crew torque Mounting (*3)		-	M5		3.5	N m	

Note * 1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value: 2.5-3.5 Nm (M5)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

ems	Symbols	Conditions		Characteristics			Units
eilis	Symbols	Conditions	min.	typ.	max.	Ullits	
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	1.0	mA
Gate-Emitter leakage current	Iges	$V_{GE} = 0V$, $V_{GE} = \pm 20V$		-	-	200	nA
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 35mA		6.0	6.5	7.0	V
	.,	V _{GE} = 15V I _C = 35A	Tj=25°C	-	2.15	2.60	- V
	V _{CE (sat)} (terminal)		Tj=125°C	-	2.50	-	
Collector-Emitter saturation voltage	(torriiiridi)		Tj=150°C	-	2.55	-	
	V _{CE} (sat)	V _{GE} = 15V I _C = 35A	Tj=25°C	-	1.85	2.30	
	(chip)		Tj=125°C	-	2.20	-	
	(Tj=150°C	-	2.25	-	
Input capacitance	Cies	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	2.9	-	nF
Turn-on time	ton			- 0.39 1.20			
Turn-on time	tr	Vcc = 600V		-	0.09	0.60	μs
	tr (i)	I _c = 35A V _{GE} = +15 / -15V		-	0.03	-	
Turn-off time	toff	$R_G = 27\Omega$		-	0.53	1.00	
Turn-on time	tf			-	0.06	0.30	
	.,	I _F = 35A	Tj=25°C	-	2.00	2.45	V
Forward on voltage	V _F (terminal)		Tj=125°C	-	2.15	-	
	(terriiriai)		Tj=150°C	-	2.10	-	
	.,	I _F = 35A	Tj=25°C	-	1.70	2.15	
	V _F (chip)		Tj=125°C	-	1.85	-	
	(GIIIP)		Tj=150°C	-	1.80	-	
Reverse recovery time	trr	I _F = 35A		-	-	0.1	μs
Zero gate voltage collector current	Ices	V _{GE} = 0V V _{CE} = 1200V		-	-	1.0	mA
Gate-Emitter leakage current	Iges	V _{CE} = 0V V _{GE} = +20 / -20V		-	-	200	nA
Collector-Emitter saturation voltage	V _{CE (sat)} (terminal)	V _{GE} = 15V	Tj=25°C	-	2.05	2.50	V
			Tj=125°C	_	2.40	-	
		Ic = 25A	Tj=150°C	-	2.45	-	
		V _{GE} = 15V I _C = 25A	Tj=25°C	-	1.85	2.30	
	VCE (sat)		Tj=125°C	-	2.20	-	
	(chip)		Tj=150°C	-	2.25	-	1
	ton	V _{CE} = 600V		-	0.39	1.20	
Turn-on time	tr	Ic = 25A		-	0.09	0.60	
	toff	V _{GE} = +15 / -15V R _G = 39Ω		-	0.53	1.00	μs
Turn-off time	tf			-	0.06	0.30	
Reverse current	IRRM			-	-	1.00	mA
orward on voltage	V _{FM} (chip)	I _F = 35A	terminal	-	1.65	2.10	.,
			chip	-	1.35	-	V
Reverse current	IRRM	V _R = 1600V		-	-	1.0	mA
		T = 25°C T = 100°C		-	5000	-	Ω
Resistance B value	R			465	495	520	
B T = 25 / 50°C			3305	3375	3450	K	

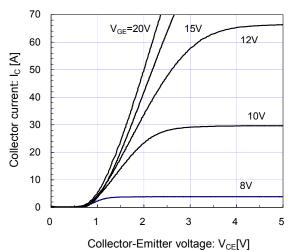
Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units	
items		Conditions	min.	typ.	max.	Ullits	
	Rth(j-c)	Inverter IGBT	-	-	0.72		
Thermal registance (1device)		Inverter FWD	-	-	0.91		
Thermal resistance (1device)		Brake IGBT	-	-	0.89	°C/W	
		Converter Diode	-	-	0.88		
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.05	-		

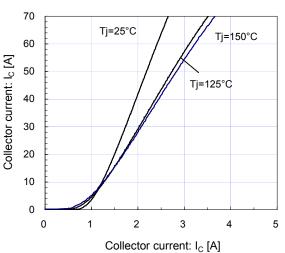
Note $^{\star}4$: This is the value which is defined mounting on the additional cooling fin with thermal compound.

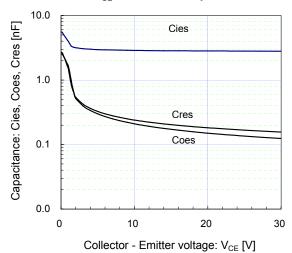
■ Characteristics (Representative)

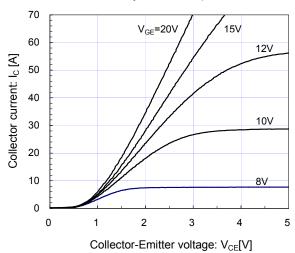
[Inverter]
Collector current vs. Collector-Emitter voltage (typ.)
Tj= 25°C / chip



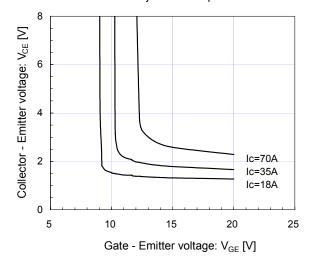
 $[\ Inverter\]$ Collector current vs. Collector-Emitter voltage (typ.) $V_{GE} = 15V\ /\ chip$







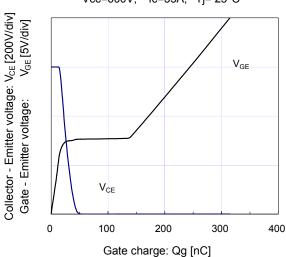
 $\label{eq:continuous} \begin{tabular}{ll} \b$



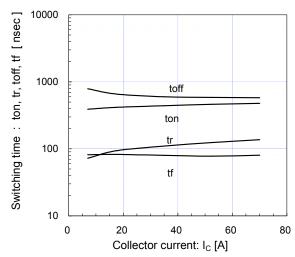
[Inverter]

Dynamic gate charge (typ.)

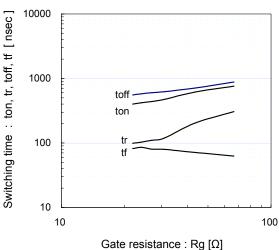
Vcc=600V, Ic=35A, Tj= 25°C



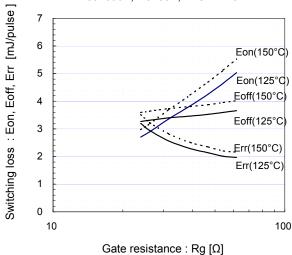
[Inverter]
Switching time vs. Collector current (typ.)
Vcc=600V, VGE=±15V, Rg=27Ω, Tj= 125°C



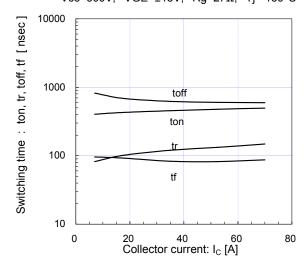
[Inverter]
Switching time vs. gate resistance (typ.)
Vcc=600V, Ic=35A, VGE=±15V, Tj= 125°C



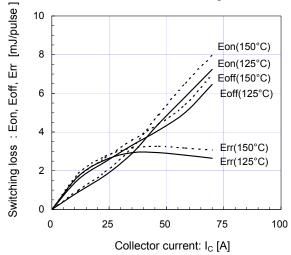
[Inverter]
Switching loss vs. gate resistance (typ.)
Vcc=600V, Ic=35A, VGE=±15V



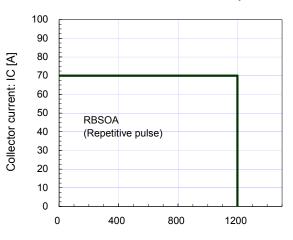
[Inverter] Switching time vs. Collector current (typ.) Vcc=600V, VGE= \pm 15V, Rg=27 Ω , Tj= 150°C



 $\label{eq:continuous} \begin{tabular}{ll} [Inverter] a \\ Switching loss vs. Collector current (typ.) \\ Vcc=600V, VGE=\pm15V, Rg=27\Omega \end{tabular}$

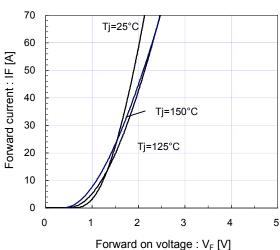


[Inverter] Reverse bias safe operating area (max.) +VGE=15V,-VGE <= 15V, RG >= 27Ω , Tj <= 125° C

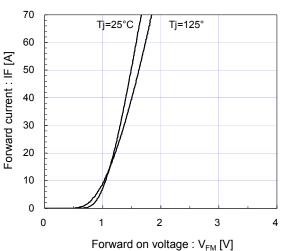


Collector-Emitter voltage : $V_{CE}[V]$

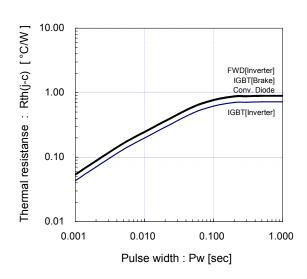
[Inverter]
Forward current vs. forward on voltage (typ.) chip



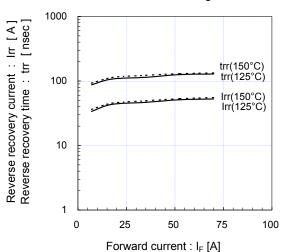
[Converter]
Forward current vs. forward on voltage (typ.) chip



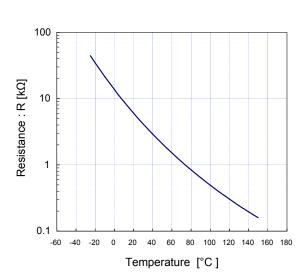
Transient thermal resistance (max.)



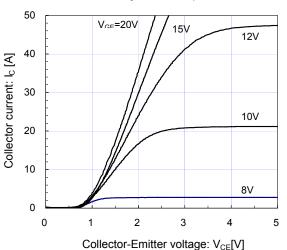
 $[\ Inverter\]$ Reverse recovery characteristics (typ.) $Vcc=600V,\ VGE=\pm15V,\ Rg=27\Omega$



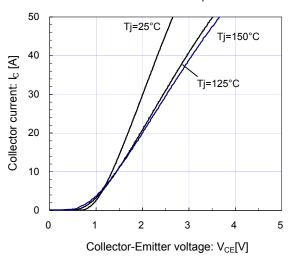
[Thermistor]
Temperature characteristic (typ.)



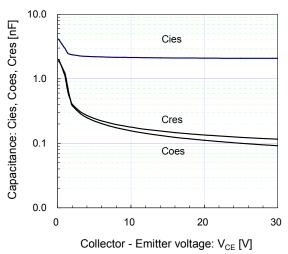
[Brake] Collector current vs. Collector-Emitter voltage (typ.) $Tj = 25^{\circ}C \text{ / chip}$



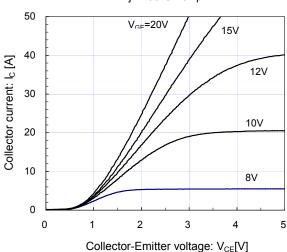
[Brake]
Collector current vs. Collector-Emitter voltage (typ.)
VGE=15V / chip



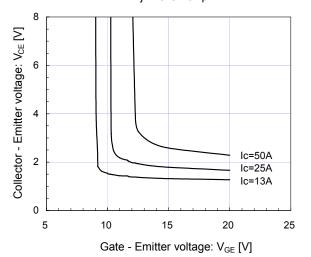
 $[\mbox{ Brake }] $$ Capacitance vs. Collector-Emitter voltage (typ.) $$ V_{GE}=0V, \ f= 1MHz, \ Tj= 25^{\circ}C $$$



 $[\ Brake \]$ Collector current vs. Collector-Emitter voltage (typ.) $Tj{=}\ 150^{\circ}C\ /\ chip$



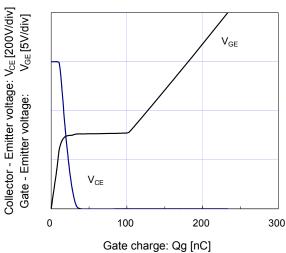
 $[\ Brake\]$ Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) $Tj = 2 \mbox{\it ff}\ C\ /\ chip$



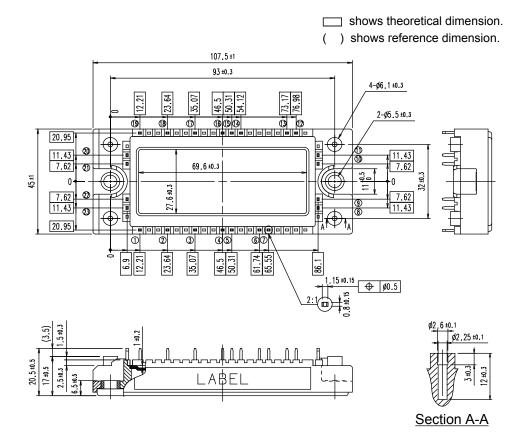
[Brake]

Dynamic gate charge (typ.)

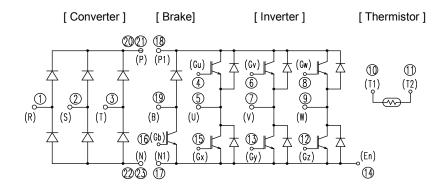
Vcc=600V, Ic=35A, Tj= 25°C



■ Outline Drawings, mm



■ Equivalent Circuit Schematic



WARNING

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- Communications equipment (terminal devices)
- Measurement equipment

- Machine tools
- Audiovisual equipment
- Electrical home appliances
- Personal equipment
- Industrial robots etc.
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• Traffic-signal control equipment

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- Emergency equipment for responding to disasters and anti-burglary devices
- Safety devices

- Medical equipment
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